

## Analog Electronic Circuits (EC2.103) : Quiz-2

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Date : 19<sup>th</sup> May, 2023, Duration : 45 minutes, Max. Marks : 10

### Instructions:

- Clearly write your valid assumptions (if any)
- You are only allowed to use own handwritten **single** A-4 sheet (both sides) as short notes
- Mobile phone, computers can not be used during the exam

1. As shown in figure 1, derive the expression for small signal input resistance  $R_{in}$  and fill in the blanks. Consider that both transistors ( $Q_1$  &  $Q_2$ ) are in active mode and symbols have their usual meanings. (Hint: Draw small signal equivalent, apply  $v_{in}$ , measure  $i_{in}$ , then  $R_{in} = \frac{v_{in}}{i_{in}}$ ) [4 Mark]

$$R_{in} = (---)r_{\pi 1} + (---)r_{\pi 2} + (---)R_E$$

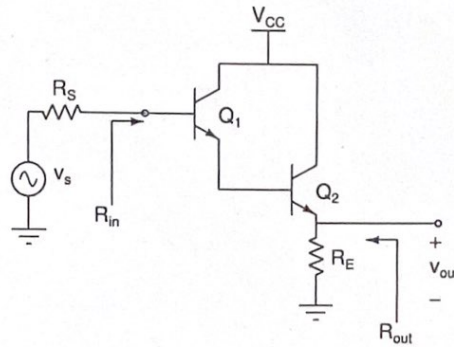


Figure 1

2. For the amplifier topology shown in figure 2, it is given that  $\beta = 100$ ,  $I_S = 6 \times 10^{-16}$  A and  $V_A = \infty$ .

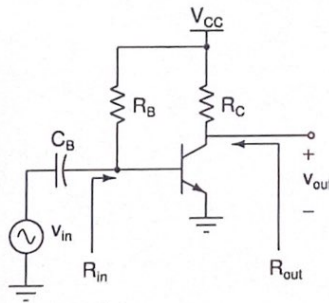


Figure 2

- (a) Draw small signal equivalent and derive voltage gain ( $A_v = \frac{v_{out}}{v_{in}}$ ). [1 Mark]
- (b) Derive the expressions for  $R_{in}$  and  $R_{out}$ . [1 Mark]
- (c) Design the amplifier to achieve following specifications:  $A_v \geq 8$ ,  $R_{out} = 1 \text{ k}\Omega$ ,  $R_{in} \geq 5 \text{ k}\Omega$ ,  $V_{CC} = 2.5 \text{ V}$ , lowest signal frequency of interest ( $f_{in_{min}}$ ) is 100 Hz and overall power dissipation  $P_{DC} \leq 1 \text{ mW}$ . Tabulate the final design parameters ( $A_v$ ,  $R_{in}$ ,  $R_{out}$ ,  $P_{DC}$ ) achieved in your design. (Hint: Design means you need to find  $R_C$ ,  $R_B$  &  $C_B$  values to satisfy the requirements.  $I_C = I_S \exp(\frac{V_{BE}}{V_T})$ ,  $I_C = \beta I_B$ ) [4 Mark]

Good luck !!